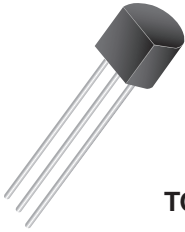
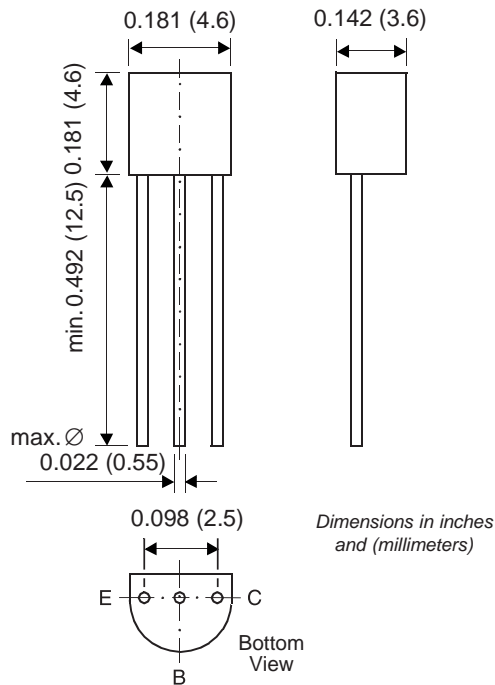


## Small Signal Transistor (NPN)



TO-226AA (TO-92)



### Features

- NPN Silicon Epitaxial Planar Transistor for switching and amplifier applications.
- As complementary type, the PNP transistor 2N3906 is recommended.
- On special request, this transistor is also manufactured in the pin configuration TO-18.
- This transistor is also available in the SOT-23 case with the type designation MMBT3904.

### Mechanical Data

**Case:** TO-92 Plastic Package

**Weight:** approx. 0.18g

**Packaging Codes/Options:**

E6/Bulk – 5K per container, 20K/box

E7/4K per Ammo mag., 20K/box

### Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

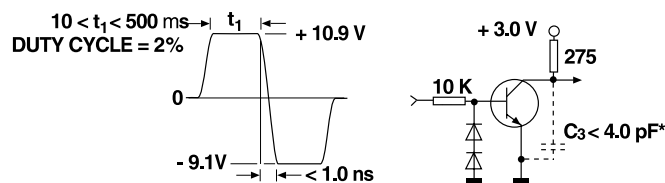
Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	40	V
Collector-Base Voltage	$V_{CBO}$	60	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current	$I_C$	200	mA
Power Dissipation $T_A = 25^\circ\text{C}$ $T_C = 25^\circ\text{C}$	$P_{tot}$	625 1.5	mW W
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	250 <sup>(1)</sup>	$^\circ\text{C/W}$
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_s$	-65 to +150	$^\circ\text{C}$

**Note:**

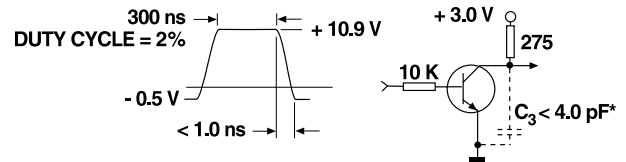
(1) Valid provided that leads are kept at ambient temperature.

## Electrical Characteristics (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0	60	—	—	V
Collector-Emitter Breakdown Voltage <sup>(1)</sup>	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	40	—	—	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 10 μA, I <sub>C</sub> = 0	6	—	—	V
Collector Saturation Voltage	V <sub>CEsat</sub>	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5 mA	— —	— —	0.2 0.3	V
Base Saturation Voltage	V <sub>BEsat</sub>	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5 mA	— —	— —	0.85 0.95	V
Collector-Emitter Cutoff Current	I <sub>CEV</sub>	V <sub>EB</sub> = 3 V, V <sub>CE</sub> = 30 V	—	—	50	nA
Emitter-Base Cutoff Current	I <sub>EBV</sub>	V <sub>EB</sub> = 3 V, V <sub>CE</sub> = 30 V	—	—	50	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 0.1 mA V <sub>CE</sub> = 1 V, I <sub>C</sub> = 1 mA V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA V <sub>CE</sub> = 1 V, I <sub>C</sub> = 50 mA V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA	40 70 100 60 30	— — 300 — —	— — — — —	—
Input Impedance	h <sub>ie</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA f = 1 kHz	1	—	10	kΩ
Voltage Feedback Ratio	h <sub>re</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA f = 1 kHz	0.5 • 10 <sup>-4</sup>	—	8 • 10 <sup>-4</sup>	—
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> = 20 V, I <sub>C</sub> = 10 mA f = 100 MHz	300	—	—	MHz
Collector-Base Capacitance	C <sub>CBO</sub>	V <sub>CB</sub> = 5 V, f = 100 kHz	—	—	4	pF
Emitter-Base Capacitance	C <sub>EBO</sub>	V <sub>CB</sub> = 0.5 V, f = 100 kHz	—	—	8	pF
Small Signal Current Gain	h <sub>fe</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA, f = 1 kHz	100	—	400	—
Output Admittance	h <sub>oe</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 1 mA, f = 1 kHz	1	—	40	μS
Noise Figure	NF	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 100 μA, R <sub>G</sub> = 1 kΩ, f = 10...15000 kHz	—	—	5	dB
Delay Time (see fig. 1)	t <sub>d</sub>	I <sub>B1</sub> = 1 mA, I <sub>C</sub> = 10 mA	—	—	35	ns
Rise Time (see fig. 1)	t <sub>r</sub>	I <sub>B1</sub> = 1 mA, I <sub>C</sub> = 10 mA	—	—	35	ns
Storage Time (see fig. 2)	t <sub>s</sub>	-I <sub>B1</sub> = I <sub>B2</sub> = 1 mA I <sub>C</sub> = 10 mA	—	—	200	ns
Fall Time (see fig. 2)	t <sub>f</sub>	-I <sub>B1</sub> = I <sub>B2</sub> = 1 mA I <sub>C</sub> = 10 mA	—	—	50	ns



**Fig. 1:** Test circuit for delay and rise time  
\* total shunt capacitance of test jig and connectors



**Fig. 2:** Test circuit for storage and fall time  
\* total shunt capacitance of test jig and connectors